



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



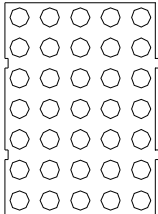
## Contact us

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**Product :**  
**1.2" DOT-MATRIX DISPLAY**

**Part Number :**  
VAOM-C12571G-BW/40  
VAOM-A12571G-BW/40

**Description**

Chip Material-G: GaP/GaP.  
Emitted Color: Yellow Green.  
Black Face & White Dot.

VAOM-C12571G-BW/40  
Column Cathode, Row Anode.

VAOM-A12571G-BW/40  
Column Anode, Row Cathode.

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Yellow Green	Unit
Power dissipation per dice	PAD	70	mW
Derating Liner from 25°C per dice	-	0.33	mA°C
Continuous forward current per dice	IAF	25	mA
Peak current per dice (duty cycle 1/10, 1kHz)	IPF	90	mA
Reverse voltage per dice	VR	5	V
Operating temperature	Topr	-25 to +85	°C
Storage temperature	Tstg	-25 to +85	°C
Solder temperature 1/16 inch below seating plane for 5 seconds at 260°C			

Electrical / Optical Characteristics and Curves at Ta=25°C

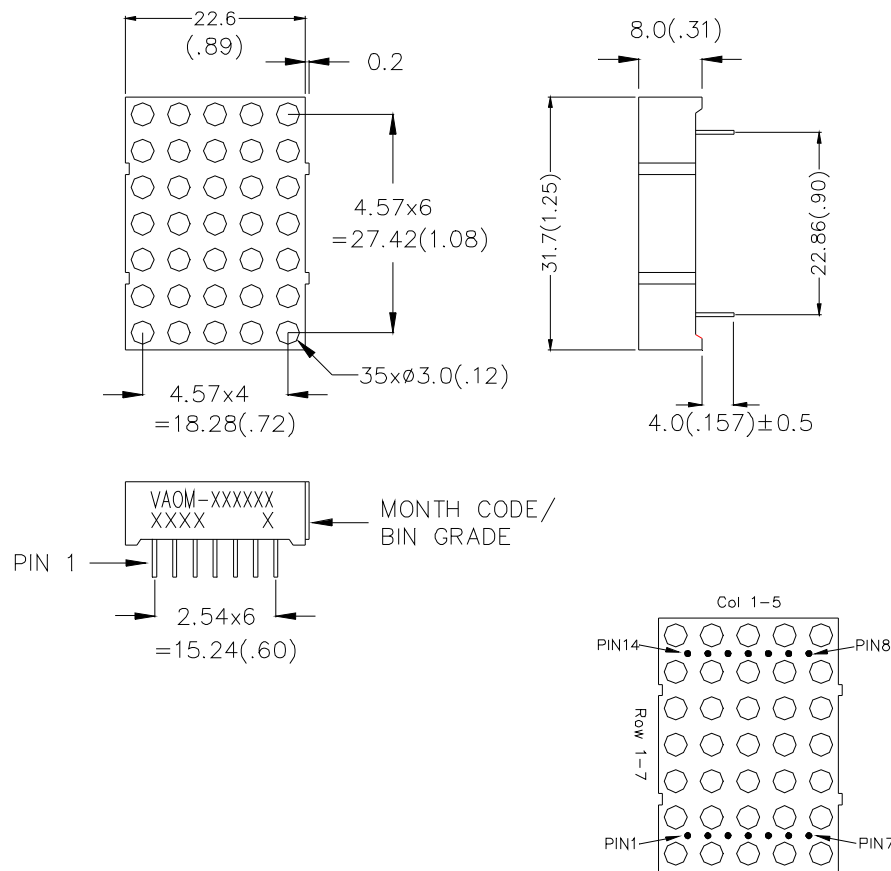
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Forward Voltage per dot	VF	IF=20 mA		2.1	2.8	V
Luminous intensity per dot	IV	IF=20 mA		12		mcd.
Peak emission wavelength	$\lambda d$	IF=20 mA		565		nm
Spectrum radiation bandwidth	$\Delta \lambda$	IF=20 mA		30		nm
Reverse Current	IR	VR=5 V			100	$\mu A$

\* Tolerance :  $\pm 20\%$ .



## Package Dimension & Internal Circuit

- \* 1.2 inch (30.42mm) Matrix height.
- \* 5\*7 array.
- \* Description: VAOM-C12571. Column Cathode , Row Anode .
- \* Description: VAOM-A12571. Column Anode , Row Cathode .

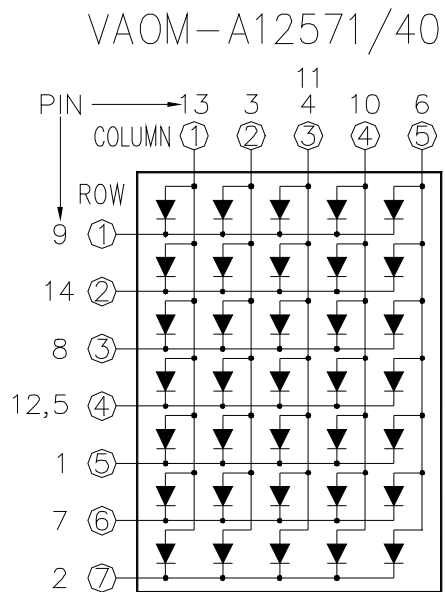
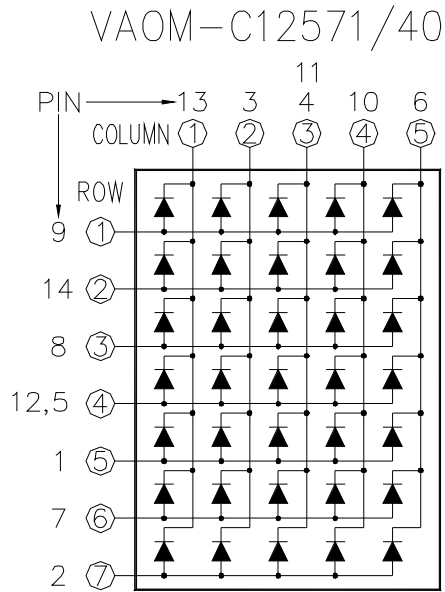


**NOTE:**

1. All pins are ø0.51(.02)
2. Dimension in millimeter (inch), and tolerance is ±0.30 (.01) unless otherwise noted.

VER\_B-08-12-P40

Internal Circuit



Cathode(-) Anode(+)

VER\_B-08-12-P40



# GREEN

## Typical Electro-optical Characteristic Curves (25°C Free Air Temperature Unless Otherwise Specified)

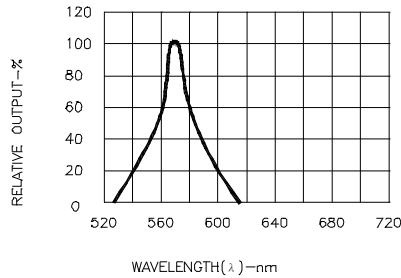


Fig.1 SPECTRAL RESPONSE

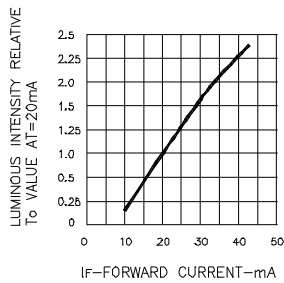


Fig.2 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

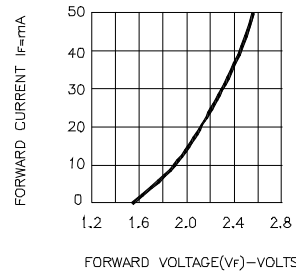


Fig.3 FORWARD CURRENT VS FORWARD VOLTAGE

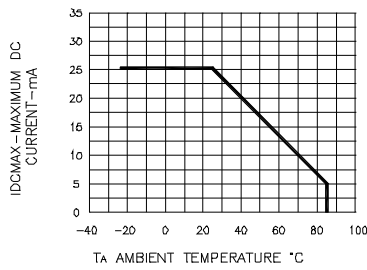


Fig.4 MAXIMUM ALLOWABLE DC CURRENT PER SEGMENT VS. AMBIENT TEMPERATURE

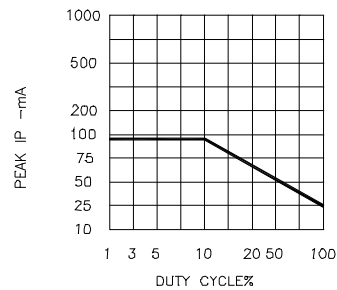


Fig.5 MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE f=1KHz)